

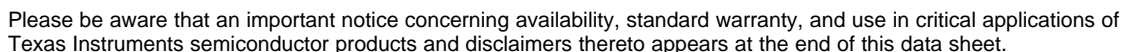
Check for Samples: [LM3501](#)

APPLICATIONS

- **LCD Bias Supplies**
- **White LED Back-Lighting**
- **Handheld Devices**
- **Digital Cameras**
- **Portable Applications**

The LM3501 is a fixed-frequency step-up DC/DC converter that is ideal for driving white LEDs for display backlighting and other lighting functions. With fully integrated synchronous switching (no external schottky diode required) and a low feedback voltage (515 mV), power efficiency of the LM3501 circuit has been optimized for lighting applications in wireless phones and other portable products (single cell Li-Ion or 3-cell NiMH battery supplies). The LM3501 operates with a fixed 1 MHz switching frequency. When used with ceramic input and output capacitors, the LM3501 provides a small, low-noise, low-cost solution.

Figure 1. Typical 3 LED Application



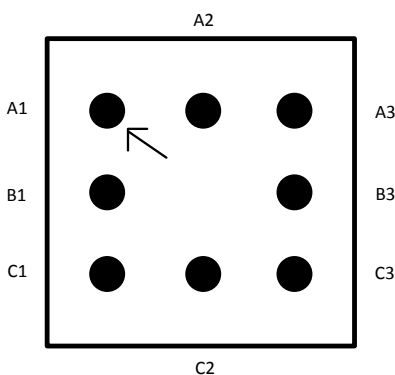
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DESCRIPTION (CONTINUED)

Two LM3501 options are available with different output voltage capabilities. The LM3501-21 has a maximum output voltage of 21V and is typically suited for driving 4 or 5 white LEDs in series. The LM3501-16 has a maximum output voltage of 16V and is typically suited for driving 3 or 4 white LEDs in series (maximum number of series LEDs dependent on LED forward voltage). If the primary white LED network should be disconnected, the LM3501 uses internal protection circuitry on the output to prevent a destructive overvoltage event.

A single external resistor is used to set the maximum LED current in LED-drive applications. The LED current can easily be adjusted by varying the analog control voltage on the control pin or by using a pulse width modulated (PWM) signal on the shutdown pin. In shutdown, the LM3501 completely disconnects the input from output, creating total isolation and preventing any leakage currents from trickling into the LEDs.

Connection Diagram



**Figure 2. 8-Bump DSBGA
Top View**

PIN DESCRIPTIONS

| Pin | Name | Function |
|-----|--------------------------|--------------------------------------------------------------------|
| A1 | AGND | Analog ground. |
| B1 | V _{IN} | Analog and Power supply input. |
| C1 | V _{OUT} | PMOS source connection for synchronous rectification. |
| C2 | V _{SW} | Switch pin. Drain connections of both NMOS and PMOS power devices. |
| C3 | GND | Power Ground. |
| B3 | FB | Output voltage feedback connection. |
| A3 | CNTRL | Analog LED current control. |
| A2 | $\overline{\text{SHDN}}$ | Shutdown control pin. |

AGND (pin A1): Analog ground pin

The analog ground pin should tie directly to the GND pin.

V_{IN} (pin B1): Analog and Power supply pin

Bypass this pin with a capacitor, as close to the device as possible, connected between the V_{IN} and GND pins.

V_{OUT} (pin C1): Source connection of internal PMOS power device

Connect the output capacitor between the V_{OUT} and GND pins as close as possible to the device.

V_{SW} (pin C2): Drain connection of internal NMOS and PMOS switch devices

Keep the inductor connection close to this pin to minimize EMI radiation.

GND (pin C3): Power ground pin

Tie directly to ground plane.

FB (pin B3): Output voltage feedback connection

Set the primary White LED network current with a resistor from the FB pin to GND. Keep the current setting resistor close to the device and connected between the FB and GND pins.

CNTRL (pin A3): Analog control of LED current

A voltage above 125 mV will begin to regulate the LED current. Decreasing the voltage below 75 mV will turn off the LEDs.

 $\overline{\text{SHDN}}$ (pin A2): Shutdown control pin

Disable the device with a voltage less than 0.3V and enable the device with a voltage greater than 1.1V. The white LED current can be controlled using a PWM signal at this pin. There is an internal pull down on the $\overline{\text{SHDN}}$ pin, the device is in a normally off state.



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

Absolute Maximum Ratings ⁽¹⁾⁽²⁾

| | |
|---------------------------------------------|---------------------------------|
| V _{IN} | –0.3V to 7.5V |
| V _{OUT} (LM3501-16) ⁽³⁾ | –0.3V to 16V |
| V _{OUT} (LM3501-21) ⁽³⁾ | –0.3V to 21V |
| V _{SW} ⁽³⁾ | –0.3V to V _{OUT} +0.3V |
| FB Voltage | –0.3V to 7.5V |
| SHDN Voltage | –0.3V to V _{IN} +0.3V |
| CNTRL | –0.3V to 7.5V |
| Maximum Junction Temperature | 150°C |
| Lead Temperature (Soldering 10 sec.) | 300°C |
| Vapor Phase (60 sec.) | 215°C |
| Infrared (15 sec.) | 220°C |
| ESD Ratings ⁽⁴⁾ | |
| Human Body Model | 2kV |
| Machine Model | 200V |

- (1) Absolute maximum ratings are limits beyond which damage to the device may occur. Operating Ratings are conditions for which the device is intended to be functional, but device parameter specifications may not be specified. For specifications and test conditions, see the Electrical Characteristics.
- (2) Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/ Distributors for availability and specifications.
- (3) This condition applies if V_{IN} < V_{OUT}. If V_{IN} > V_{OUT}, a voltage greater than V_{IN} + 0.3V should not be applied to the V_{OUT} or V_{SW} pins.
- (4) The human body model is a 100 pF capacitor discharged through a 1.5 kΩ resistor into each pin. The machine model is a 200 pF capacitor discharged directly into each pin.

Operating Conditions

| | |
|----------------------------------------|-----------------|
| Junction Temperature ⁽¹⁾ | –40°C to +125°C |
| Supply Voltage | 2.7V to 7V |
| CNTRL Max. | 2.7V |

- (1) The maximum allowable power dissipation is a function of the maximum operating junction temperature, T_{J(MAX)}, the junction-to-ambient thermal resistance, θ_{JA}, and the ambient temperature, T_A. See the *Thermal Properties* section for the thermal resistance. The maximum allowable power dissipation at any ambient temperature is calculated using: P_D (MAX) = (T_{J(MAX)} – T_A)/θ_{JA}. Exceeding the maximum allowable power dissipation will cause excessive die temperature.

Thermal Properties

| | |
|--------------------------------------------------------------------------|--------|
| Junction to Ambient Thermal Resistance (θ _{JA}) ⁽¹⁾ | 75°C/W |
|--------------------------------------------------------------------------|--------|

- (1) Junction-to-ambient thermal resistance (θ_{JA}) is highly application and board-layout dependent. The 75°C/W figure provided was measured on a 4-layer test board conforming to JEDEC standards. In applications where high maximum power dissipation exists, special care must be paid to thermal dissipation issues when designing the board layout.

Electrical Characteristics

Specifications in standard type face are for $T_A = 25^\circ\text{C}$ and those in **boldface type** apply over the **Operating Temperature Range of $T_A = -10^\circ\text{C}$ to $+85^\circ\text{C}$** . Unless otherwise specified $V_{IN} = 2.7\text{V}$ and specifications apply to both LM3501-16 and LM3501-21.

| Symbol | Parameter | Conditions | Min (1) | Typ (2) | Max (1) | Units |
|-----------------|-------------------------------------------|-------------------------------------------------------------------------|--------------|------------|--------------|---------------|
| I_Q | Quiescent Current, Device Not Switching | $FB > 0.54\text{V}$ | | 0.95 | 1.2 | mA |
| | Quiescent Current, Device Switching | $FB = 0\text{V}$ | | 2 | 2.5 | |
| | Shutdown | $\overline{\text{SHDN}} = 0\text{V}$ | | 0.1 | 2 | μA |
| V_{FB} | Feedback Voltage | $\text{CNTRL} = 2.7\text{V}$, $V_{IN} = 2.7\text{V}$ to 7V | 0.485 | 0.515 | 0.545 | V |
| | | $\text{CNTRL} = 1\text{V}$, $V_{IN} = 2.7\text{V}$ to 7V | 0.14 | 0.19 | 0.24 | |
| ΔV_{FB} | Feedback Voltage Line Regulation | $V_{IN} = 2.7\text{V}$ to 7V | | 0.1 | 0.5 | %/V |
| I_{CL} | Switch Current Limit (LM3501-16) | $V_{IN} = 2.7\text{V}$, Duty Cycle = 80% | 275 | 400 | 480 | mA |
| | | $V_{IN} = 3.0\text{V}$, Duty Cycle = 70% | 255 | 400 | 530 | |
| | Switch Current Limit (LM3501-21) | $V_{IN} = 2.7\text{V}$, Duty Cycle = 70% | 420 | 640 | 770 | |
| | | $V_{IN} = 3.0\text{V}$, Duty Cycle = 63% | 450 | 670 | 800 | |
| I_B | FB Pin Bias Current | $FB = 0.5\text{V}$ (3) | | 45 | 200 | nA |
| V_{IN} | Input Voltage Range | | 2.7 | | 7.0 | V |
| $R_{DS(on)}$ | NMOS Switch $R_{DS(on)}$ | $V_{IN} = 2.7\text{V}$, $I_{SW} = 300\text{mA}$ | | | 0.43 | Ω |
| | PMOS Switch $R_{DS(on)}$ | $V_{OUT} = 6\text{V}$, $I_{SW} = 300\text{mA}$ | | 1.3 | 2.3 | |
| D_{Limit} | Duty Cycle Limit (LM3501-16) | $FB = 0\text{V}$ | 80 | 87 | | % |
| | Duty Cycle Limit (LM3501-21) | $FB = 0\text{V}$ | 85 | 94 | | |
| F_{SW} | Switching Frequency | | 0.85 | 1.0 | 1.15 | MHz |
| I_{SD} | $\overline{\text{SHDN}}$ Pin Current (4) | $\overline{\text{SHDN}} = 5.5\text{V}$ | | 1.8 | 4 | μA |
| | | $\overline{\text{SHDN}} = 2.7\text{V}$ | | 1 | 2.5 | |
| | | $\overline{\text{SHDN}} = \text{GND}$ | | 0.1 | | |
| I_{CNTRL} | CNTRL Pin Current (4) | $V_{CNTRL} = 2.7\text{V}$ | | 10 | 20 | μA |
| | | $V_{CNTRL} = 1\text{V}$ | | 4 | 15 | |
| I_L | Switch Leakage Current (LM3501-16) | $V_{SW} = 15\text{V}$ | | 0.01 | 0.5 | μA |
| | Switch Leakage Current (LM3501-21) | $V_{SW} = 20\text{V}$ | | 0.01 | 2.0 | |
| UVP | Input Undervoltage Lockout | ON Threshold | 2.4 | 2.5 | 2.6 | V |
| | | OFF Threshold | 2.3 | 2.4 | 2.5 | |
| OVP | Output Overvoltage Protection (LM3501-16) | ON Threshold | 15 | 15.5 | 16 | V |
| | | OFF Threshold | 14 | 14.6 | 15 | |
| | Output Overvoltage Protection (LM3501-21) | ON Threshold | 20 | 20.5 | 21 | V |
| | | OFF Threshold | 19 | 19.5 | 20 | |

- (1) All limits specified at room temperature (standard typeface) and at temperature extremes (bold typeface). All room temperature limits are production tested, specified through statistical analysis or specified by design. All limits at temperature extremes are specified via correlation using standard Statistical Quality Control (SQC) methods. All limits are used to calculate Average Outgoing Quality Level (AOQL).
- (2) Typical numbers are at 25°C and represent the most likely norm.
- (3) Feedback current flows out of the pin.
- (4) Current flows into the pin.

Electrical Characteristics (continued)

Specifications in standard type face are for $T_A = 25^\circ\text{C}$ and those in **boldface type** apply over the **Operating Temperature Range of $T_A = -10^\circ\text{C}$ to $+85^\circ\text{C}$** . Unless otherwise specified $V_{IN} = 2.7\text{V}$ and specifications apply to both LM3501-16 and LM3501-21.

| Symbol | Parameter | Conditions | Min (1) | Typ (2) | Max (1) | Units |
|------------------------------------|-----------------------------------------|-----------------------------------------------------------------|------------|------------|------------|---------------|
| I_{Vout} | V_{OUT} Bias Current (LM3501-16) | $V_{OUT} = 15\text{V}$, $\overline{\text{SHDN}} = 1.5\text{V}$ | | 260 | 400 | μA |
| | V_{OUT} Bias Current (LM3501-21) | $V_{OUT} = 20\text{V}$, $\overline{\text{SHDN}} = 1.5\text{V}$ | | 300 | 460 | |
| I_{VL} | PMOS Switch Leakage Current (LM3501-16) | $V_{OUT} = 15\text{V}$, $V_{SW} = 0\text{V}$ | | 0.01 | 3 | μA |
| | PMOS Switch Leakage Current (LM3501-21) | $V_{OUT} = 20\text{V}$, $V_{SW} = 0\text{V}$ | | 0.01 | 3 | |
| CNTRL Threshold | | LED power off | | 75 | | mV |
| | | LED power on | | 125 | | |
| $\overline{\text{SHDN}}$ Threshold | $\overline{\text{SHDN}}$ low | | | 0.65 | 0.3 | V |
| | $\overline{\text{SHDN}}$ High | | 1.1 | 0.65 | | |

Specifications in standard type face are for $T_J = 25^\circ\text{C}$ and those in **boldface type** apply over the full **Operating Temperature Range ($T_J = -40^\circ\text{C}$ to $+125^\circ\text{C}$)**. Unless otherwise specified $V_{IN} = 2.7\text{V}$ and specifications apply to both LM3501-16 and LM3501-21.

| Symbol | Parameter | Conditions | Min (1) | Typ (2) | Max (1) | Units |
|-----------------|-----------------------------------------------------|----------------------------------------------------------------------|--------------|------------|--------------|---------------|
| I_Q | Quiescent Current, Device Not Switching | $\text{FB} > 0.54\text{V}$ | | 0.95 | 1.2 | mA |
| | Quiescent Current, Device Switching | $\text{FB} = 0\text{V}$ | | 2 | 2.5 | |
| | Shutdown | $\overline{\text{SHDN}} = 0\text{V}$ | | 0.1 | 2 | μA |
| V_{FB} | Feedback Voltage | $\text{CNTRL} = 2.7\text{V}$, $V_{IN} = 2.7\text{V}$ to 7V | 0.485 | 0.515 | 0.545 | V |
| | | $\text{CNTRL} = 1\text{V}$, $V_{IN} = 2.7\text{V}$ to 7V | 0.14 | 0.19 | 0.24 | |
| ΔV_{FB} | Feedback Voltage Line Regulation | $V_{IN} = 2.7\text{V}$ to 7V | | 0.1 | 0.5 | %/V |
| I_{CL} | Switch Current Limit (LM3501-16) | $V_{IN} = 3.0\text{V}$, Duty Cycle = 70% | | 400 | | mA |
| | Switch Current Limit (LM3501-21) | $V_{IN} = 3.0\text{V}$, Duty Cycle = 63% | | 670 | | |
| I_B | FB Pin Bias Current | $\text{FB} = 0.5\text{V}$ ⁽³⁾ | | 45 | 200 | nA |
| V_{IN} | Input Voltage Range | | 2.7 | | 7.0 | V |
| $R_{DS(on)}$ | NMOS Switch $R_{DS(on)}$ | $V_{IN} = 2.7\text{V}$, $I_{SW} = 300\text{mA}$ | | | 0.43 | Ω |
| | PMOS Switch $R_{DS(on)}$ | $V_{OUT} = 6\text{V}$, $I_{SW} = 300\text{mA}$ | | 1.3 | 2.3 | |
| D_{Limit} | Duty Cycle Limit (LM3501-16) | $\text{FB} = 0\text{V}$ | | 87 | | % |
| | Duty Cycle Limit (LM3501-21) | $\text{FB} = 0\text{V}$ | | 94 | | |
| F_{SW} | Switching Frequency | | 0.8 | 1.0 | 1.2 | MHz |
| I_{SD} | $\overline{\text{SHDN}}$ Pin Current ⁽⁴⁾ | $\overline{\text{SHDN}} = 5.5\text{V}$ | | 1.8 | 4 | μA |
| | | $\overline{\text{SHDN}} = 2.7\text{V}$ | | 1 | 2.5 | |
| | | $\overline{\text{SHDN}} = \text{GND}$ | | 0.1 | | |

- (1) All limits specified at room temperature (standard typeface) and at temperature extremes (bold typeface). All room temperature limits are production tested, specified through statistical analysis or specified by design. All limits at temperature extremes are specified via correlation using standard Statistical Quality Control (SQC) methods. All limits are used to calculate Average Outgoing Quality Level (AOQL).
- (2) Typical numbers are at 25°C and represent the most likely norm.
- (3) Feedback current flows out of the pin.
- (4) Current flows into the pin.

Specifications in standard type face are for $T_J = 25^\circ\text{C}$ and those in **boldface type** apply over the full **Operating Temperature Range ($T_J = -40^\circ\text{C}$ to $+125^\circ\text{C}$)**. Unless otherwise specified $V_{IN} = 2.7\text{V}$ and specifications apply to both LM3501-16 and LM3501-21.

| Symbol | Parameter | Conditions | Min (1) | Typ (2) | Max (1) | Units |
|------------------------------------|-------------------------------------------|-----------------------------------------------------------------|------------|------------|------------|---------------|
| I_{CNTRL} | CNTRL Pin Current ⁽⁴⁾ | $V_{CNTRL} = 2.7\text{V}$ | | 10 | 20 | μA |
| | | $V_{CNTRL} = 1\text{V}$ | | 4 | 15 | |
| I_L | Switch Leakage Current (LM3501-16) | $V_{SW} = 15\text{V}$ | | 0.01 | 0.5 | μA |
| | Switch Leakage Current (LM3501-21) | $V_{SW} = 20\text{V}$ | | 0.01 | 2.0 | |
| UVP | Input Undervoltage Lockout | ON Threshold | 2.4 | 2.5 | 2.6 | V |
| | | OFF Threshold | 2.3 | 2.4 | 2.5 | |
| OVP | Output Overvoltage Protection (LM3501-16) | ON Threshold | 15 | 15.5 | 16 | V |
| | | OFF Threshold | 14 | 14.6 | 15 | |
| | Output Overvoltage Protection (LM3501-21) | ON Threshold | 20 | 20.5 | 21 | |
| | | OFF Threshold | 19 | 19.5 | 20 | |
| I_{Vout} | V_{OUT} Leakage Current (LM3501-16) | $V_{OUT} = 15\text{V}$, $\overline{\text{SHDN}} = 1.5\text{V}$ | | 260 | 400 | μA |
| | V_{OUT} Leakage Current (LM3501-21) | $V_{OUT} = 20\text{V}$, $\overline{\text{SHDN}} = 1.5\text{V}$ | | 300 | 460 | |
| I_{VL} | PMOS Switch Leakage Current (LM3501-16) | $V_{OUT} = 15\text{V}$, $V_{SW} = 0\text{V}$ | | 0.01 | 3 | μA |
| | PMOS Switch Leakage Current (LM3501-21) | $V_{OUT} = 20\text{V}$, $V_{SW} = 0\text{V}$ | | 0.01 | 3 | |
| CNTRL Threshold | | LED power off | | 75 | | mV |
| | | LED power on | | 125 | | |
| $\overline{\text{SHDN}}$ Threshold | $\overline{\text{SHDN}}$ low | | | 0.65 | 0.3 | V |
| | $\overline{\text{SHDN}}$ High | | 1.1 | 0.65 | | |

Typical Performance Characteristics

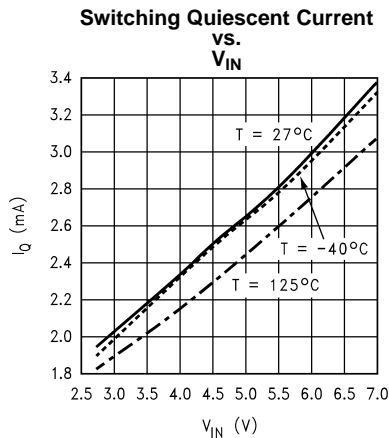


Figure 3.

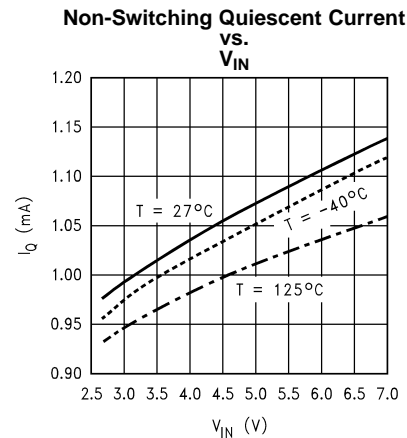


Figure 4.

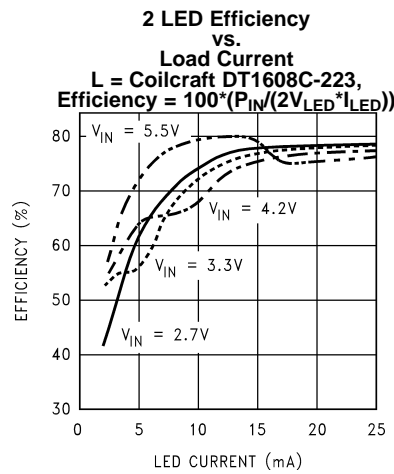


Figure 5.

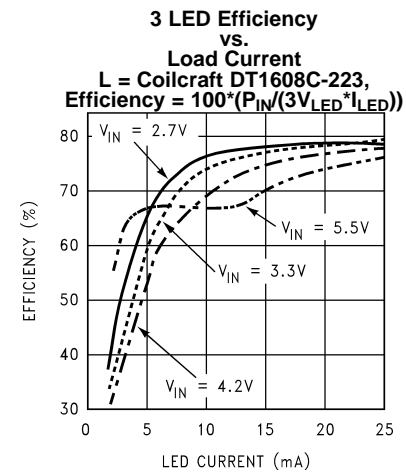


Figure 6.

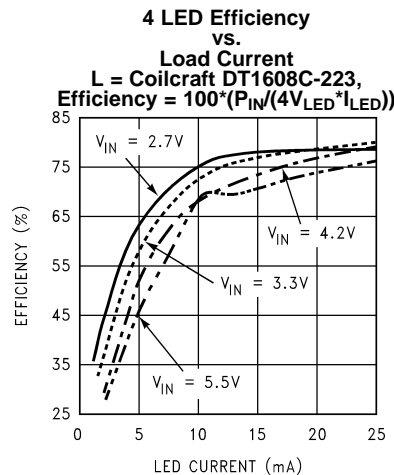


Figure 7.

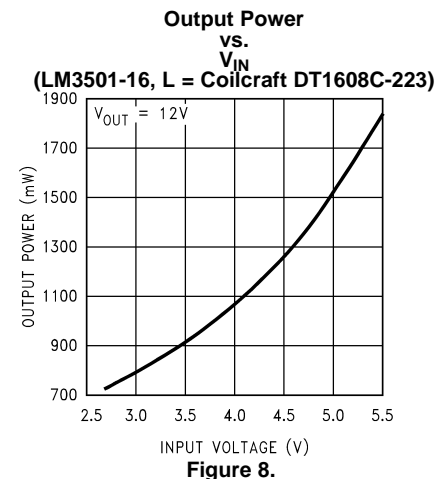


Figure 8.

Typical Performance Characteristics (continued)

**Output Power
vs.
Temperature
(LM3501-16, L = Coilcraft DT1608C-223)**

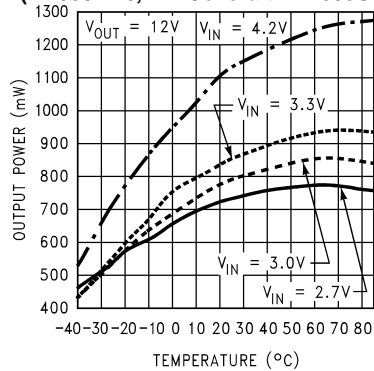


Figure 9.

**FB Pin Current
vs.
Temperature**

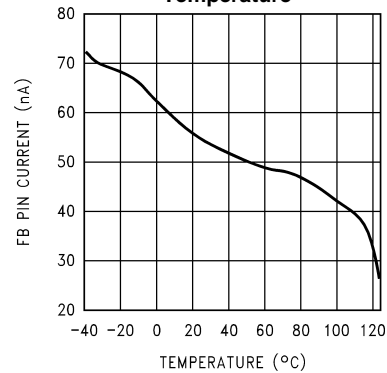


Figure 10.

**SHDN Pin Current
vs.
SHDN Pin Voltage**

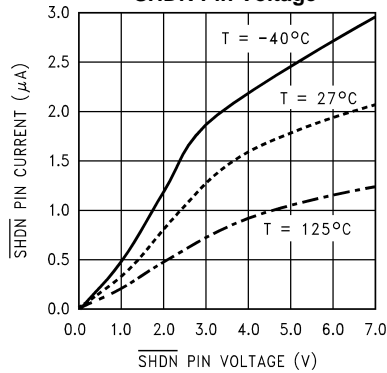


Figure 11.

**CNTRL Pin Current
vs.
CNTRL Pin Voltage**

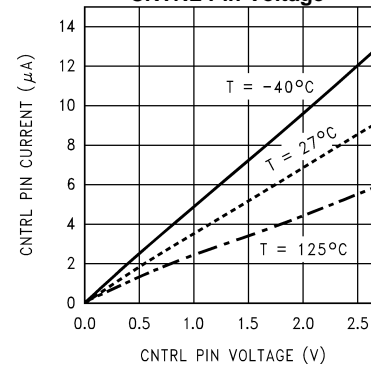


Figure 12.

**FB Voltage
vs.
CNTRL Voltage**

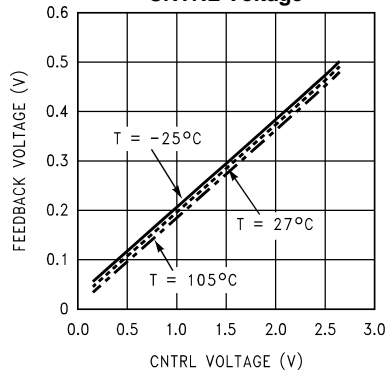


Figure 13.

**Switch Current Limit
vs.
VIN
(LM3501-16)**

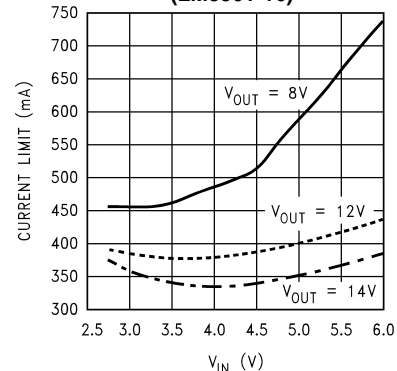


Figure 14.

Typical Performance Characteristics (continued)

Switch Current Limit
vs.
Temperature

(LM3501-16, $V_{OUT} = 8V$)

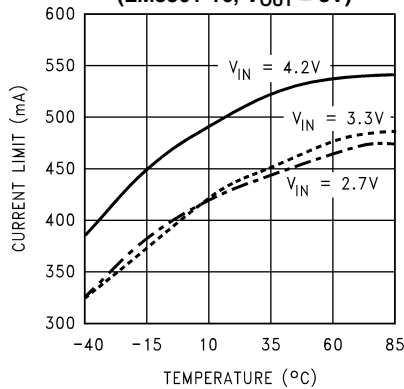


Figure 15.

Switch Current Limit
vs.
Temperature

(LM3501-16, $V_{OUT} = 12V$)

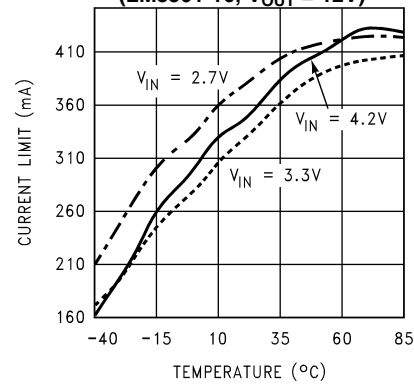


Figure 16.

Switch Current Limit
vs.
 V_{IN}

(LM3501-21)

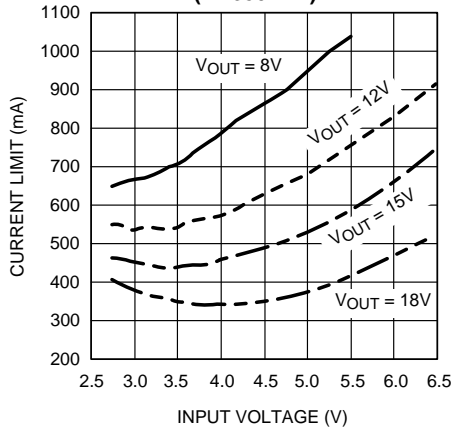


Figure 17.

Switch Current Limit
vs.
Temperature

(LM3501-21, $V_{OUT} = 8V$)

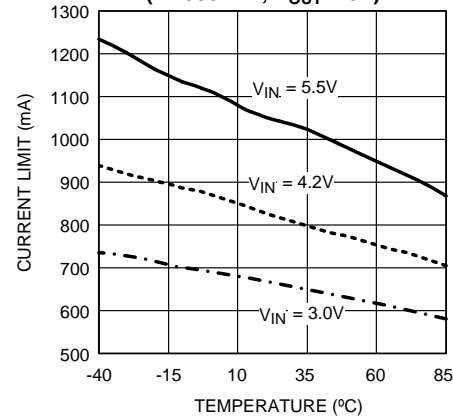


Figure 18.

Switch Current Limit
vs.
Temperature

(LM3501-21, $V_{OUT} = 12V$)

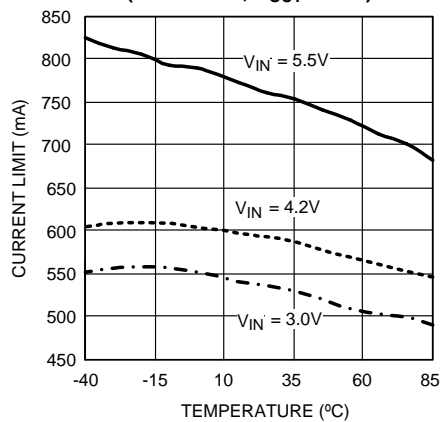


Figure 19.

Switch Current Limit
vs.
Temperature

(LM3501-21, $V_{OUT} = 18V$)

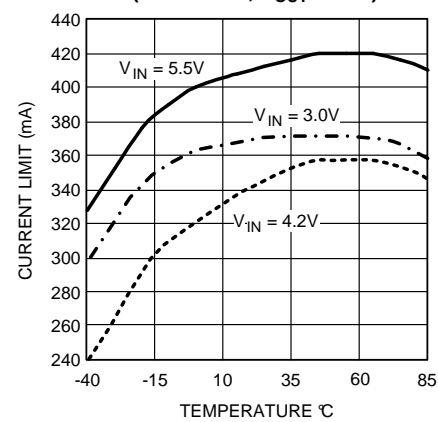


Figure 20.

Typical Performance Characteristics (continued)

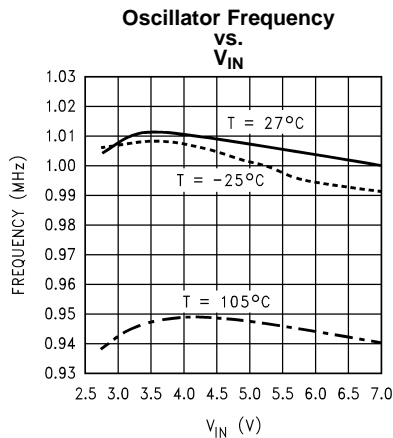


Figure 21.

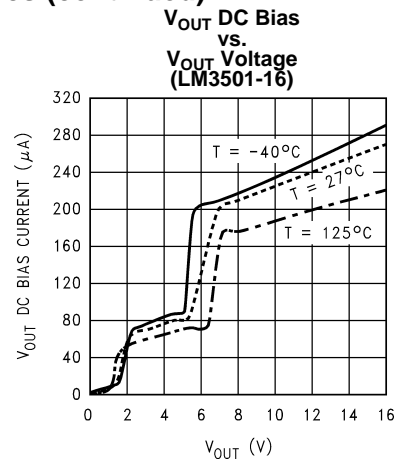


Figure 22.

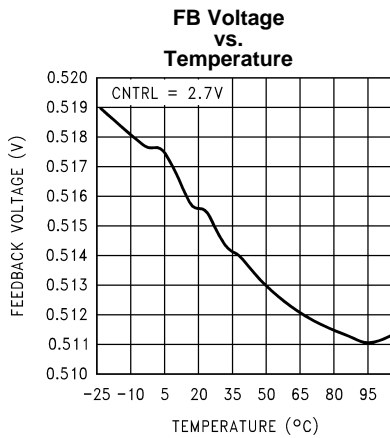


Figure 23.

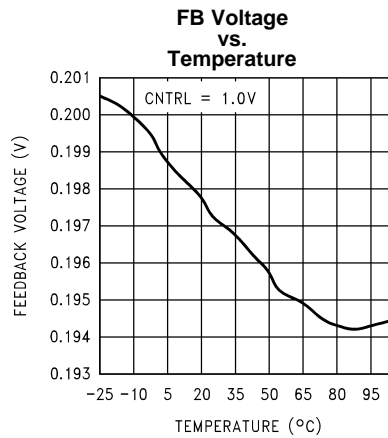


Figure 24.

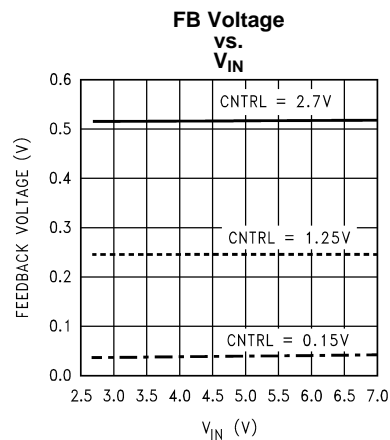


Figure 25.

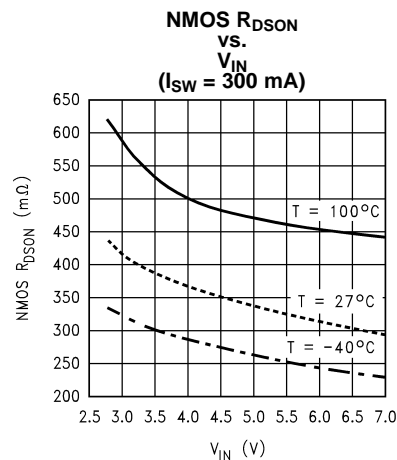


Figure 26.

Typical Performance Characteristics (continued)

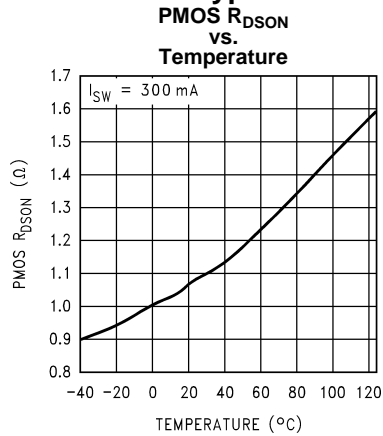
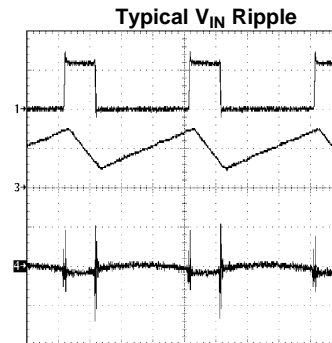


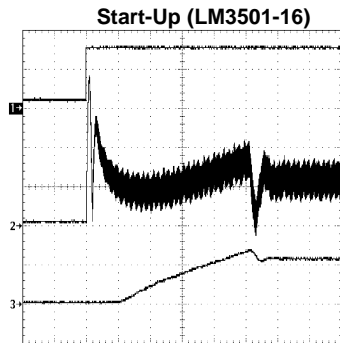
Figure 27.



3 LEDs, $R_{LED} = 22\Omega$, $V_{IN} = 3.0\text{V}$, $CNTRL = 2.7\text{V}$

- 1) SW, 10 V/div, DC
- 3) I_L , 100 mA/div, DC
- 4) V_{IN} , 100 mV/div, AC
- T = 250 ns/div

Figure 28.

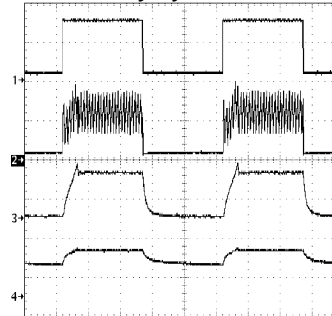


3 LEDs, $R_{LED} = 22\Omega$, $V_{IN} = 3.0\text{V}$, $CNTRL = 2.7\text{V}$

- 1) $\overline{\text{SHDN}}$, 1 V/div, DC
- 2) I_L , 100 mA/div, DC
- 3) I_{LED} , 20 mA/div, DC
- T = 100 μs /div

Figure 29.

$\overline{\text{SHDN}}$ Pin Duty Cycle Control Waveforms

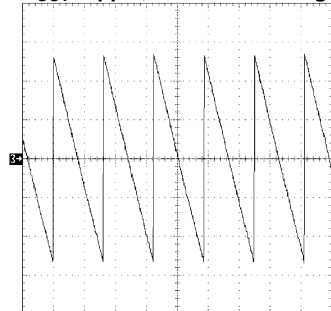


LM3501-16, 3 LEDs, $R_{LED} = 22\Omega$, $V_{IN} = 3.0\text{V}$, $\overline{\text{SHDN}}$ frequency = 200 Hz

- 1) $\overline{\text{SHDN}}$, 1 V/div, DC
- 2) I_L , 100 mA/div, DC
- 3) I_{LED} , 20 mA/div, DC
- 4) V_{OUT} , 10 V/div, DC
- T = 1 ms/div

Figure 30.

Typical V_{OUT} Ripple, OVP Functioning (LM3501-16)

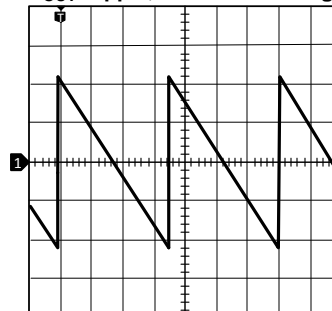


V_{OUT} open circuit and equals approximately 15V DC, $V_{IN} = 3.0\text{V}$

- 3) V_{OUT} , 200 mV/div, AC
- T = 1 ms/div

Figure 31.

Typical V_{OUT} Ripple, OVP Functioning (LM3501-21)



V_{OUT} open circuit and equals approximately 20V DC, $V_{IN} = 3.0\text{V}$

- 1) V_{OUT} , 200 mV/div, AC
- T = 400 μs /div

Figure 32.

Operation

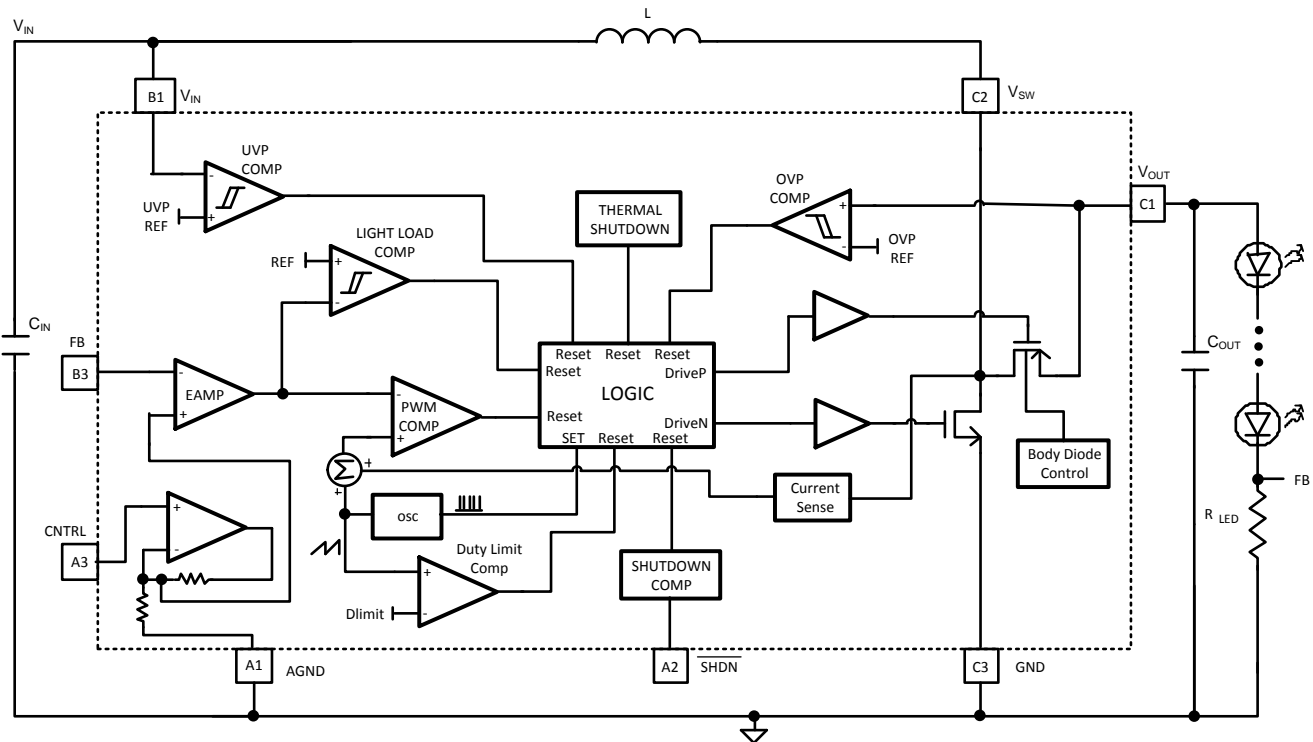


Figure 33. LM3501 Block Diagram

The LM3501 utilizes a synchronous Current Mode PWM control scheme to regulate the feedback voltage over almost all load conditions. The DC/DC controller acts as a controlled current source ideal for white LED applications. The LM3501 is internally compensated thus eliminating the requirement for any external compensation components providing a compact overall solution. The operation can best be understood referring to the block diagram in Figure 33. At the start of each cycle, the oscillator sets the driver logic and turns on the NMOS power device conducting current through the inductor and turns off the PMOS power device isolating the output from the V_{SW} pin. The LED current is supplied by the output capacitor when the NMOS power device is active. During this cycle, the output voltage of the EAMP controls the current through the inductor. This voltage will increase for larger loads and decrease for smaller loads limiting the peak current in the inductor minimizing EMI radiation. The EAMP voltage is compared with a voltage ramp and the sensed switch voltage. Once this voltage reaches the EAMP output voltage, the PWM COMP will then reset the logic turning off the NMOS power device and turning on the PMOS power device. The inductor current then flows through the PMOS power device to the white LED load and output capacitor. The inductor current recharges the output capacitor and supplies the current for the white LED branches. The oscillator then sets the driver logic again repeating the process. The Duty Limit Comp is always operational preventing the NMOS power switch from being on more than one cycle and conducting large amounts of current.

The LM3501 has dedicated protection circuitry active during normal operation to protect the IC and the external components. The Thermal Shutdown circuitry turns off both the NMOS and PMOS power devices when the die temperature reaches excessive levels. The LM3501 has a UVP Comp that disables both the NMOS and PMOS power devices when battery voltages are too low preventing an on state of the power devices which could conduct large amounts of current. The OVP Comp prevents the output voltage from increasing beyond 15.5V (LM3501-16) and 20.5V (LM3501-21) when the primary white LED network is removed or if there is an LED failure, allowing the use of small (16V for LM3501-16 and 25V for LM3501-21) ceramic capacitors at the output. This comparator has hysteresis that will regulate the output voltage between 15.5V and 14.6V typically for the LM3501-16, and between 20.5V and 19.5V for the LM3501-21. The LM3501 features a shutdown mode that reduces the supply current to 0.1 μ A and isolates the input and output of the converter. The CNTRL pin can be used to change the white LED current. A CNTRL voltage above 125 mV will enable power to the LEDs and a voltage lower than 75 mV will turn off the power to the LEDs.

APPLICATION INFORMATION

ADJUSTING LED CURRENT

The maximum White LED current is set using the following equation:

$$I_{LED} = V_{FB(MAX)}/R_{LED} \quad (1)$$

The LED current can be controlled using an external DC voltage. The recommended operating range for the voltage on the CNTRL pin is 0V to 2.7V. When CNTRL is 2.7V, FB = 0.515V (typ.) The FB voltage will continue to increase if CNTRL is brought above 2.7V (not recommended). The CNTRL to FB voltage relationship is:

$$FB = 0.191 * CNTRL \quad (2)$$

The LED current can be controlled using a PWM signal on the \overline{SHDN} pin with frequencies in the range of 100 Hz (greater than visible frequency spectrum) to 1 kHz. For controlling LED currents down to the μA levels, it is best to use a PWM signal frequency between 200-500 Hz. The LM3501 LED current can be controlled with PWM signal frequencies above 1 kHz but the controllable current decreases with higher frequency. The maximum LED current would be achieved using the equation above with 100% duty cycle, ie. the \overline{SHDN} pin always high.

Applying a voltage greater than 125 mV to the CNTRL pin will begin regulating current to the LEDs. A voltage below 75 mV will prevent application or regulation of the LED current.

LED-DRIVE CAPABILITY

The maximum number of LEDs that can be driven by the LM3501 is limited by the output voltage capability of the LM3501. When using the LM3501 in the typical application configuration, with LEDs stacked in series between the V_{OUT} and FB pins, the maximum number of LEDs that can be placed in series (N_{MAX}) is dependent on the maximum LED forward voltage (V_{F-MAX}), the voltage of the LM3501 feedback pin ($V_{FB-MAX} = 0.545V$), and the minimum output overvoltage protection level of the chosen LM3501 option (LM3501-16: $OVP_{MIN} = 15V$; LM3501-21: $OVP_{MIN} = 20V$). For the circuit to function properly, the following inequality must be met:

$$(N_{MAX} \times V_{F-MAX}) + 0.545V \leq OVP_{MIN} \quad (3)$$

When inserting a value for maximum LED VF, LED forward voltage variation over the operating temperature range should be considered. The table below provides maximum LED voltage numbers for the LM3501-16 and LM3501-21 in the typical application circuit configuration (with 3, 4, 5, 6, or 7 LEDs placed in series between the V_{OUT} and FB pins).

| # of LEDs (in series) | Maximum LED V_F | |
|--------------------------|-------------------|-----------|
| | LM3501-16 | LM3501-21 |
| 3 | 4.82V | 6.49V |
| 4 | 3.61V | 4.86V |
| 5 | 2.89V | 3.89V |
| 6 | X | 3.24V |
| 7 | X | 2.78V |

For the LM3501 to operate properly, the output voltage must be kept above the input voltage during operation. For most applications, this requires a minimum of 2 LEDs (total of 6V or more) between the FB and V_{OUT} pins.

OUTPUT OVERVOLTAGE PROTECTION

The LM3501 contains dedicated circuitry for monitoring the output voltage. In the event that the primary LED network is disconnected from the LM3501-16, the output voltage will increase and be limited to 15.5V (typ.). There is a 900 mV hysteresis associated with this circuitry which will cause the output to fluctuate between 15.5V and 14.6V (typ.) if the primary network is disconnected. In the event that the network is reconnected regulation will begin at the appropriate output voltage. The 15.5V limit allows the use of 16V 1 μF ceramic output capacitors creating an overall small solution for white LED applications.

In the event that the primary LED network is disconnected from the LM3501-21, the output voltage will increase and be limited to 20.5V (typ.). There is a 1V hysteresis associated with this circuitry which will cause the output to fluctuate between 20.5V and 19.5V (typ.) if the primary network is disconnected. In the event that the network is reconnected regulation will begin at the appropriate output voltage. The 20.5V limit allows the use of 25V 1 µF ceramic output capacitors.

RELIABILITY AND THERMAL SHUTDOWN

The maximum continuous pin current for the 8 pin thin DSBGA package is 535 mA. When driving the device near its power output limits the V_{SW} pin can see a higher DC current than 535 mA (see [INDUCTOR SELECTION](#) section for average switch current). To preserve the long term reliability of the device the average switch current should not exceed 535 mA.

The LM3501 has an internal thermal shutdown function to protect the die from excessive temperatures. The thermal shutdown trip point is typically 150°C. There is a hysteresis of typically 35°C so the die temperature must decrease to approximately 115°C before the LM3501 will return to normal operation.

INDUCTOR SELECTION

The inductor used with the LM3501 must have a saturation current greater than the cycle by cycle peak inductor current (see [Table 1](#) below). Choosing inductors with low DCR decreases power losses and increases efficiency.

The minimum inductor value required for the LM3501-16 can be calculated using the following equation:

$$L > \frac{V_{IN} R_{DS(on)}}{0.29} \left(\frac{D}{D'} - 1 \right) \quad (4)$$

The minimum inductor value required for the LM3501-21 can be calculated using the following equation:

$$L > \frac{V_{IN} R_{DS(on)}}{0.58} \left(\frac{D}{D'} - 1 \right) \quad (5)$$

For both equations above, L is in µH, V_{IN} is the input supply of the chip in Volts, $R_{DS(on)}$ is the ON resistance of the NMOS power switch found in [Typical Performance Characteristics](#) in ohms and D is the duty cycle of the switching regulator. The above equation is only valid for D greater than or equal to 0.5. For applications where the minimum duty cycle is less than 0.5, a 22 µH inductor is the typical recommendation for use with most applications. Bench-level verification of circuit performance is required in these special cases, however. The duty cycle, D, is given by the following equation:

$$D' = \frac{V_{IN}}{V_{OUT}} = 1 - D \quad (6)$$

where V_{OUT} is the voltage at pin C1.

Table 1. Typical Peak Inductor Current (mA)⁽¹⁾

| VIN (V) | # LEDs (in series) | LED Current | | | | | |
|------------|-----------------------|-------------|----------|----------|----------|----------|----------|
| | | 15 mA | 20 mA | 30 mA | 40 mA | 50 mA | 60 mA |
| 2.7 | 2 | 82 | 100 | 134 | 160 | 204 | 234 |
| | 3 | 118 | 138 | 190 | 244 | 294 | 352 |
| | 4 | 142 | 174 | 244 | 322 | X | X |
| | 5 | 191 | 232 | 319 | 413 | X | X |
| 3.3 | 2 | 76 | 90 | 116 | 136 | 172 | 198 |
| | 3 | 110 | 126 | 168 | 210 | 250 | 290 |
| | 4 | 132 | 158 | 212 | 270 | 320 | X |
| | 5 | 183 | 216 | 288 | 365 | 446 | X |

(1) $C_{IN} = C_{OUT} = 1 \mu F$, $L = 22 \mu H$, 160 mΩ DCR max. Coilcraft DT1608C-2232 and 3 LED applications: LM3501-16 or LM3501-21; LED $V_F = 3.77V$ at 20mA; $T_A = 25^\circ C$ 4 LED applications: LM3501-16 or LM3501-21; LED $V_F = 3.41V$ at 20mA; $T_A = 25^\circ C$ 5 LED applications: LM3501-21 only; LED $V_F = 3.28V$ at 20mA; $T_A = 25^\circ C$

Table 1. Typical Peak Inductor Current (mA)⁽¹⁾ (continued)

| VIN (V) | # LEDs (in series) | LED Current | | | | | |
|------------|-----------------------|-------------|----------|----------|----------|----------|----------|
| | | 15 mA | 20 mA | 30 mA | 40 mA | 50 mA | 60 mA |
| 4.2 | 2 | 64 | 76 | 96 | 116 | 142 | 162 |
| | 3 | 102 | 116 | 148 | 180 | 210 | 246 |
| | 4 | 122 | 146 | 186 | 232 | 272 | 318 |
| | 5 | 179 | 206 | 263 | 324 | 388 | 456 |

The typical cycle-by-cycle peak inductor current can be calculated from the following equation:

$$I_{PK} \approx \frac{I_{OUT}}{\eta D'} + \frac{V_{IN} D}{2 L F_{SW}} \quad (7)$$

where I_{OUT} is the total load current, F_{SW} is the switching frequency, L is the inductance and η is the converter efficiency of the total driven load. A good typical number to use for η is 0.8. The value of η can vary with load and duty cycle. The average inductor current, which is also the average V_{SW} pin current, is given by the following equation:

$$I_{L(AVE)} \approx \frac{I_{OUT}}{\eta D'} \quad (8)$$

The maximum output current capability of the LM3501 can be estimated with the following equation:

$$I_{OUT} \approx \eta D' \left(I_{CL} - \frac{V_{IN} D}{2 L F_{SW}} \right) \quad (9)$$

where I_{CL} is the current limit. Some recommended inductors include but are not limited to:

Coilcraft DT1608C series

Coilcraft DO1608C series

TDK VLP4612 series

TDK VLP5610 series

TDK VLF4012A series

CAPACITOR SELECTION

Choose low ESR ceramic capacitors for the output to minimize output voltage ripple. Multilayer X7R or X5R type ceramic capacitors are the best choice. For most applications, a 1 μ F ceramic output capacitor is sufficient.

Local bypassing for the input is needed on the LM3501. Multilayer X7R or X5R ceramic capacitors with low ESR are a good choice for this as well. A 1 μ F ceramic capacitor is sufficient for most applications. However, for some applications at least a 4.7 μ F ceramic capacitor may be required for proper startup of the LM3501. Using capacitors with low ESR decreases input voltage ripple. For additional bypassing, a 100 nF ceramic capacitor can be used to shunt high frequency ripple on the input. Some recommended capacitors include but are not limited to:

TDK C2012X7R1C105K

Taiyo-Yuden EMK212BJ105 G

LAYOUT CONSIDERATIONS

The input bypass capacitor C_{IN} , as shown in [Figure 33](#), must be placed close to the device and connect between the V_{IN} and GND pins. This will reduce copper trace resistance which effects the input voltage ripple of the IC. For additional input voltage filtering, a 100 nF bypass capacitor can be placed in parallel with C_{IN} to shunt any high frequency noise to ground. The output capacitor, C_{OUT} , should also be placed close to the LM3501 and connected directly between the V_{OUT} and GND pins. Any copper trace connections for the C_{OUT} capacitor can increase the series resistance, which directly effects output voltage ripple and efficiency. The current setting

resistor, R_{LED} , should be kept close to the FB pin to minimize copper trace connections that can inject noise into the system. The ground connection for the current setting resistor should connect directly to the GND pin. The AGND pin should connect directly to the GND pin. Not connecting the AGND pin directly, as close to the chip as possible, may affect the performance of the LM3501 and limit its current driving capability. Trace connections made to the inductor should be minimized to reduce power dissipation, EMI radiation and increase overall efficiency. It is good practice to keep the V_{SW} routing away from sensitive pins such as the FB pin. Failure to do so may inject noise into the FB pin and affect the regulation of the device. See Figure 34 and Figure 35 for an example of a good layout as used for the LM3501 evaluation board.

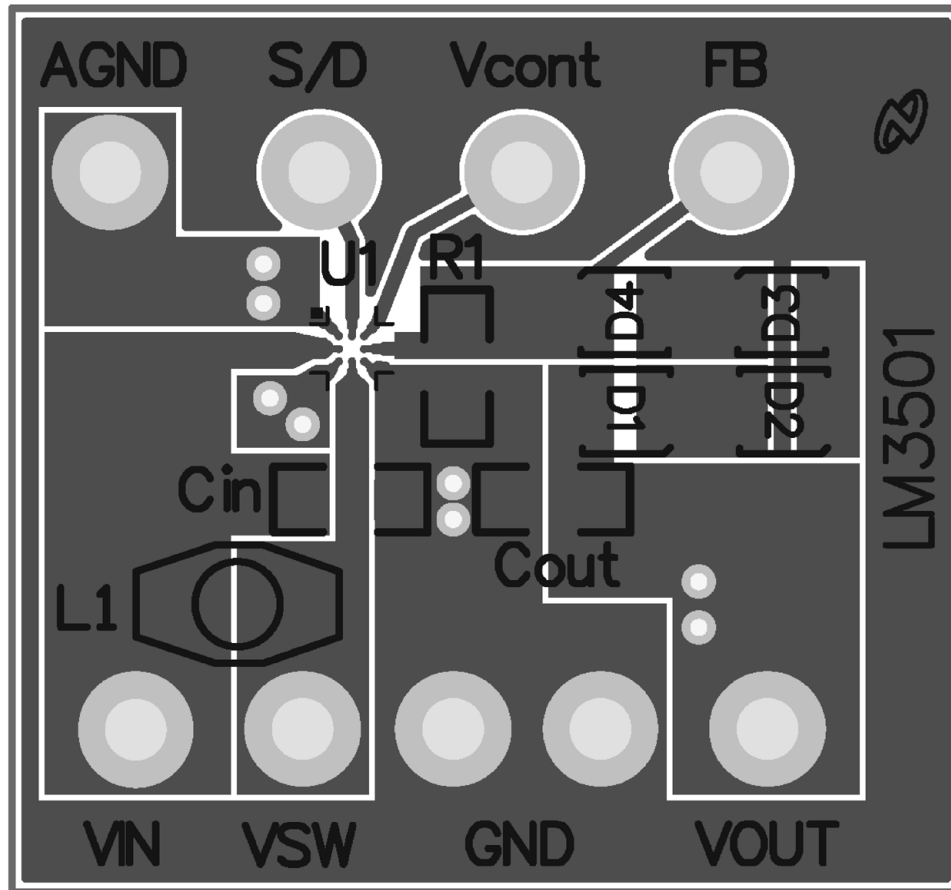
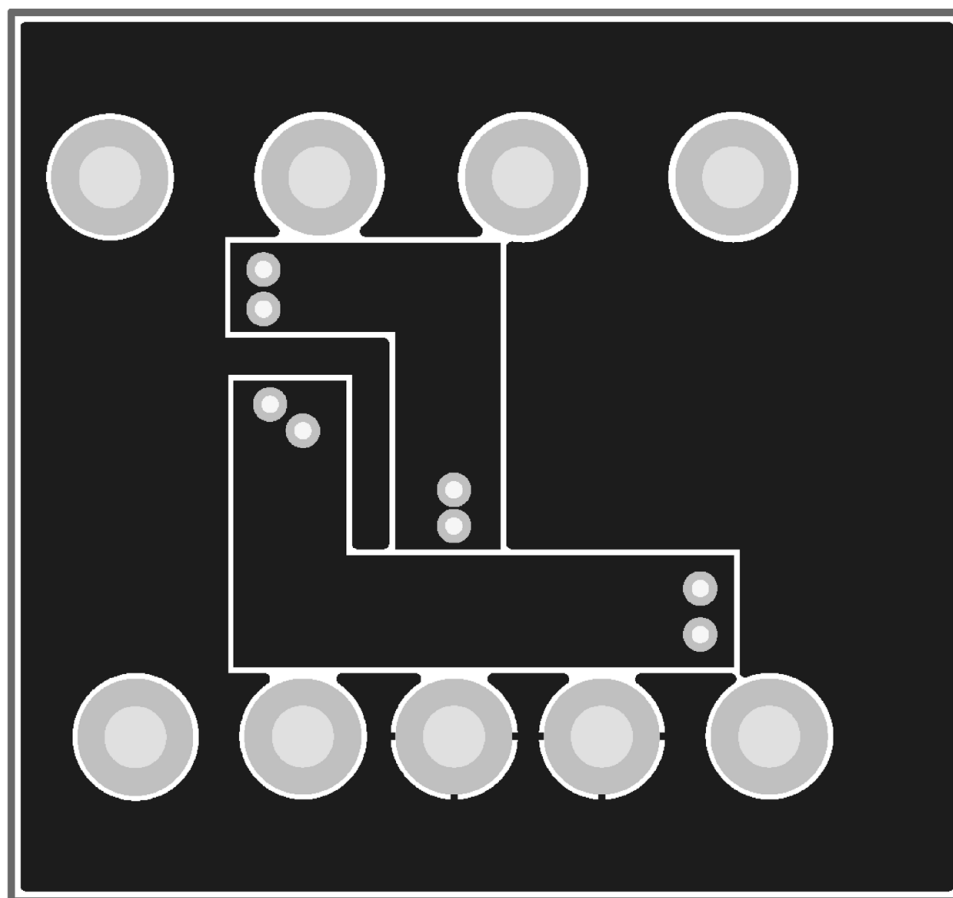


Figure 34. Evaluation Board Layout (2X Magnification)
Top Layer



**Figure 35. Evaluation Board Layout (2X Magnification)
Bottom Layer (as viewed from the top)**

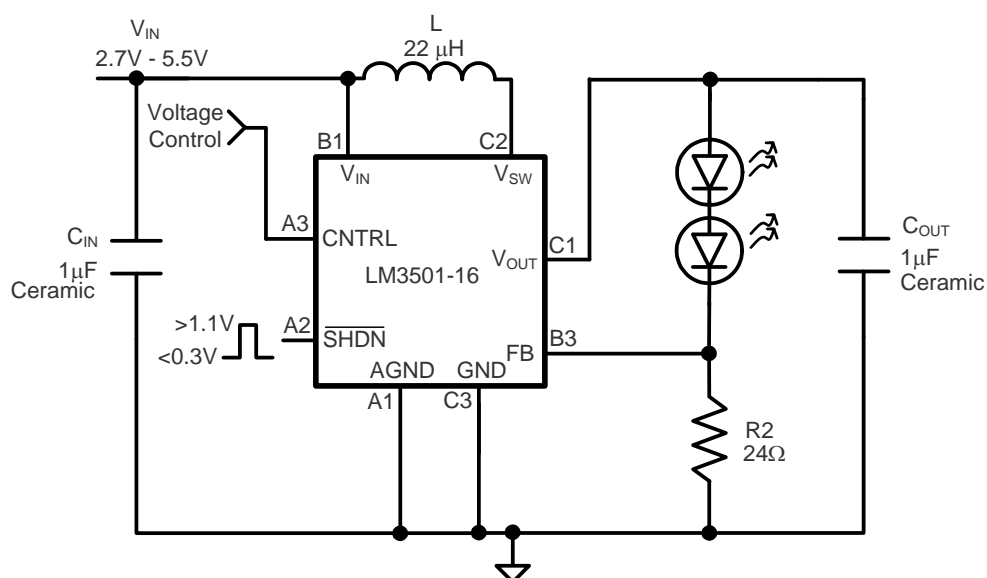


Figure 36. 2 White LED Application

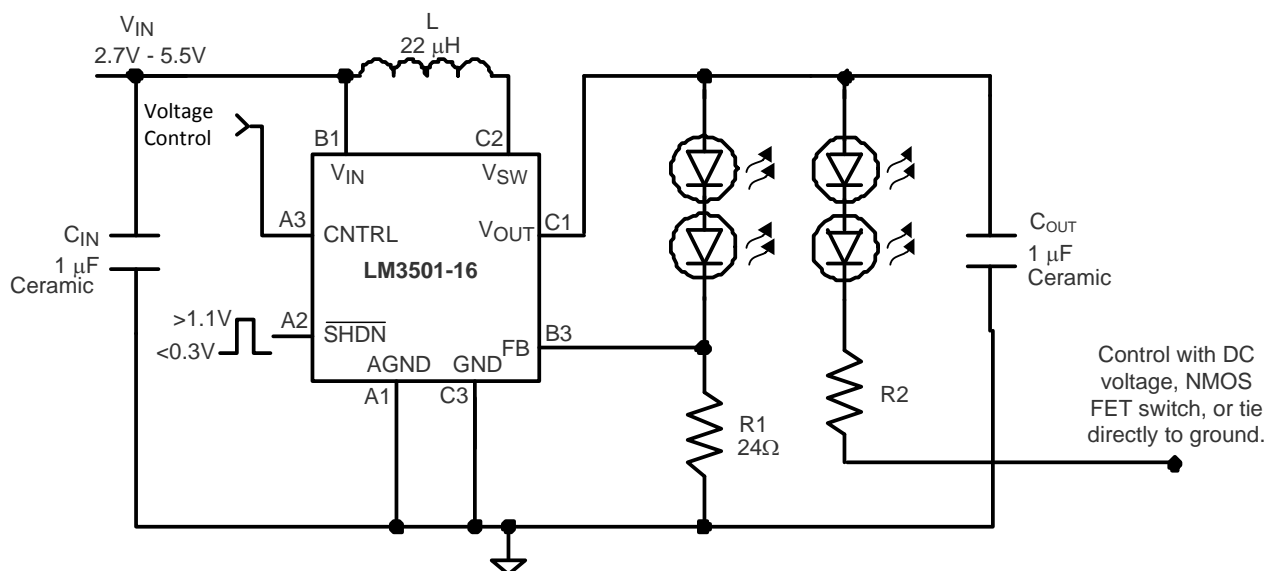


Figure 37. Multiple 2 LED String Application

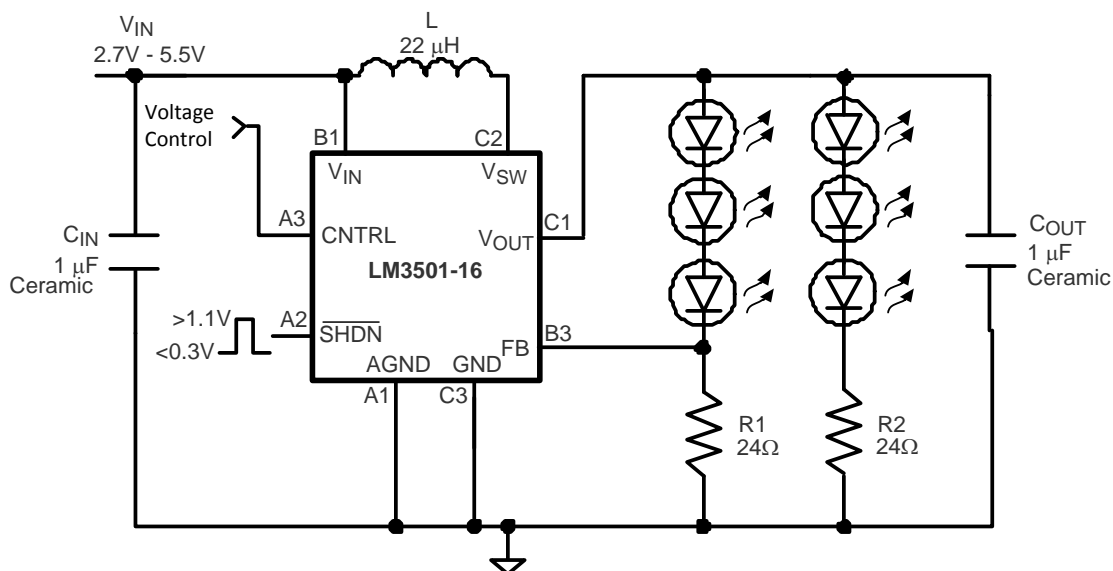


Figure 38. Multiple 3 LED String Application

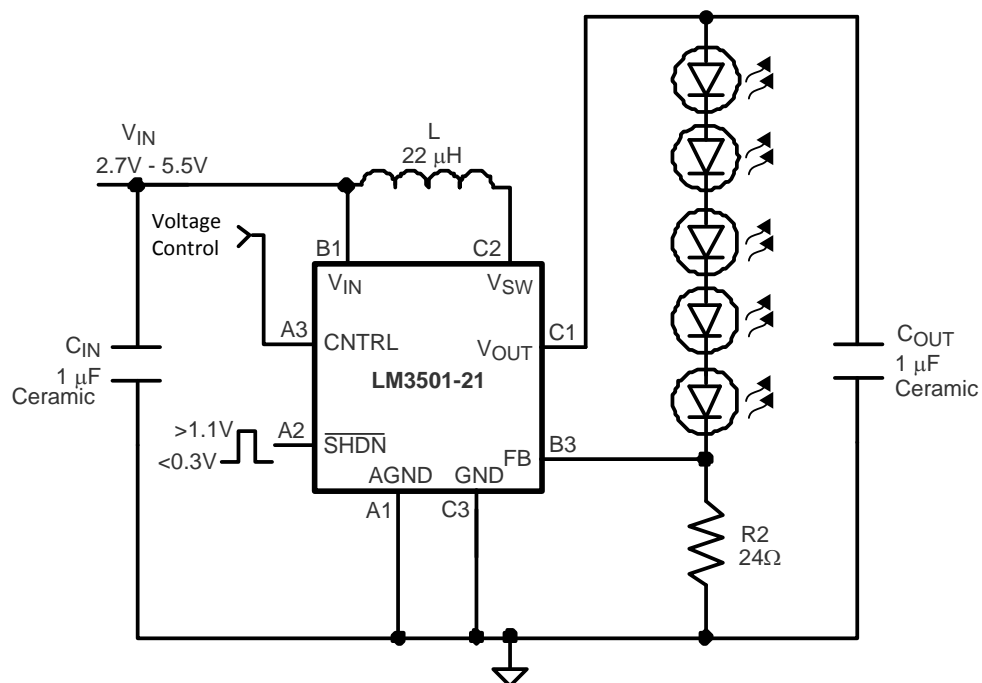


Figure 39. LM3501-21 5 LED Application

REVISION HISTORY

| Changes from Revision B (May 2013) to Revision C | Page |
|------------------------------------------------------------|--------------------|
| • Changed layout of National Data Sheet to TI format | 20 |

PACKAGING INFORMATION

| Orderable Device | Status (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan (2) | Lead finish/ Ball material (6) | MSL Peak Temp (3) | Op Temp (°C) | Device Marking (4/5) | Samples |
|------------------|---------------|--------------|--------------------|------|----------------|-----------------|--------------------------------------|----------------------|--------------|-------------------------|-------------------------|
| LM3501TL-16/NOPB | ACTIVE | DSBGA | YZR | 8 | 250 | RoHS & Green | SNAGCU | Level-1-260C-UNLIM | -40 to 85 | S 19 | Samples |

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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TAPE AND REEL INFORMATION


*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|------------------|--------------|-----------------|------|-----|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| LM3501TL-16/NOPB | DSBGA | YZR | 8 | 250 | 178.0 | 8.4 | 2.08 | 2.08 | 0.76 | 4.0 | 8.0 | Q1 |

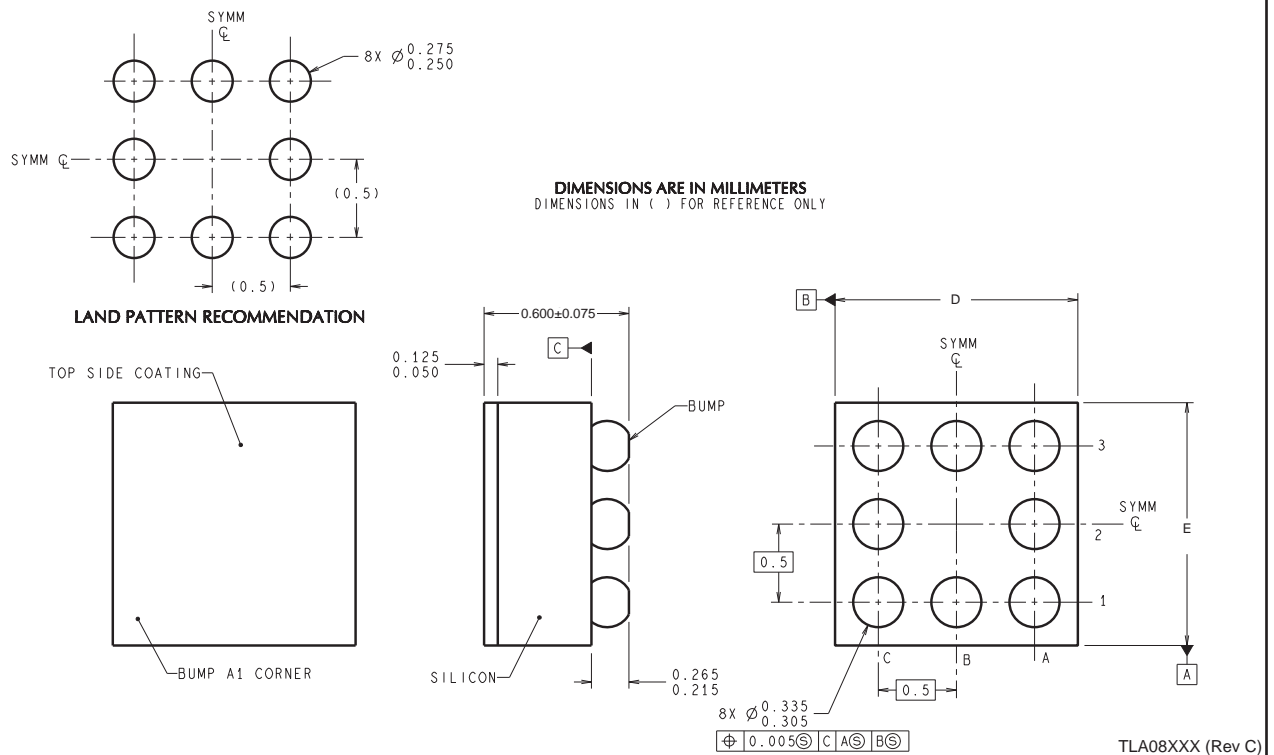
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|------------------|--------------|-----------------|------|-----|-------------|------------|-------------|
| LM3501TL-16/NOPB | DSBGA | YZR | 8 | 250 | 210.0 | 185.0 | 35.0 |

YZR0008



D: Max = 1.972 mm, Min = 1.911 mm

E: Max = 1.972 mm, Min = 1.911 mm

4215045/A 12/12

NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
B. This drawing is subject to change without notice.

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